



75V NPN MEDIUM POWER TRANSISTOR IN SOT89

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirement of Automotive Applications.

Features

- BV_{CEO} > 75V
- I_C = 3A High Continuous Current
- I_{CM} = 10A Peak Pulse Current
- High Gain Holds up $h_{FE} > 300 @ I_C=1A$
- Low Equivalent On-Resistance; $R_{CE(SAT)} = 78m\Omega$ at 4.5A
- Excellent h_{FE} Characteristics up to 10A
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

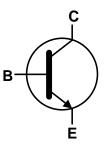
- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.05 grams (Approximate)

Applications

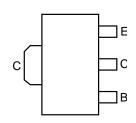
- Emergency Lighting Circuits
- Motor Driving (Including DC Fans)
- Solenoid, Relay and Actuator Drivers
- DC DC Modules
- Backlight Inverters
- Power Switches
- MOSFET Gate Drivers







Device Symbol



Top View Pin-Out

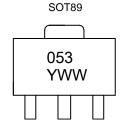
Ordering Information (Notes 4 and 5)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
FCX1053AQTA	053	7	12	1,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



053 = Product Type Marking Code YWW = Date Code Marking Y = Last Digit of Year (ex: 7 = 2017) WW = Week Code (01 to 53)



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	150	V
Collector-Emitter Voltage	V _{CEO}	75	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	3	Α
Base Current	I _B	500	mA
Peak Pulse Current	I _{CM}	10	Α

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 6)		1		
Power Dissipation	(Note 7)	P_{D}	1.6	W	
	(Note 8)		2.0		
	(Note 6)		125	°C/W	
Thermal Resistance, Junction to Ambient Air	(Note 7)	$R_{\theta JA}$	78		
	(Note 8)		62.5		
Thermal Resistance, Junction to Lead	$R_{ heta JL}$	3.6	°C/W		
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C		

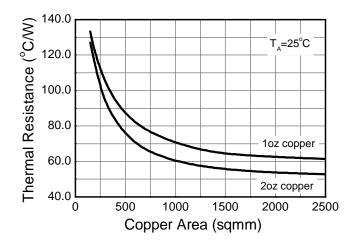
ESD Ratings (Note 10)

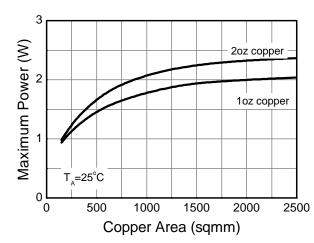
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

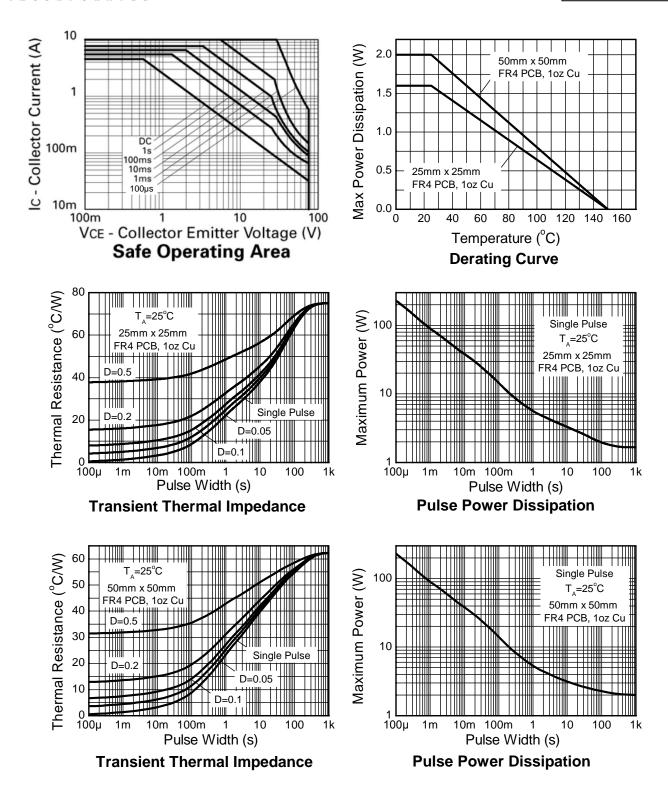
- 6. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 7. Same as note 6, except the device is mounted on 25mm x 25mm 1oz copper.
- 8. Same as note 6, except the device is mounted on 50mm x 50mm 1oz copper.
- 9. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information











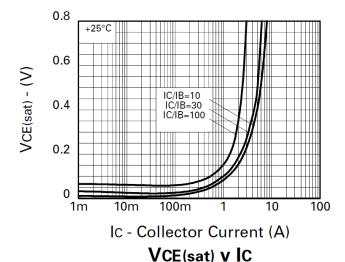
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

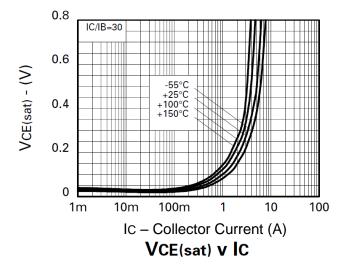
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	150	250	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage	BV _{CES}	150	250	_	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	75	100	_	V	$I_C = 10mA$
Collector-Emitter Breakdown Voltage	BV _{CEV}	150	250	_	V	$I_C = 100\mu A, V_{EB} = 1V$
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.8	_	V	I _E = 100μA
Collector Cutoff Current	I _{CBO}	_	0.9	50	nA	V _{CB} = 120V
Collector Cutoff Current	I _{CES}	_	1.5	50	nA	V _{CES} = 120V
Emitter Cutoff Current	I _{EBO}	_	0.3	20	nA	V _{EB} = 5.6V
DC Current Transfer Static Ratio (Note 11)	h _{FE}	270 300 300 40 —	440 450 450 60 20	_ 1200 _ _ _ _	_	$\begin{split} &I_{C} = 10 \text{mA}, \ V_{CE} = 2 \text{V} \\ &I_{C} = 0.5 \text{A}, \ V_{CE} = 2 \text{V} \\ &I_{C} = 1 \text{A}, \ V_{CE} = 2 \text{V} \\ &I_{C} = 4.5 \text{A}, \ V_{CE} = 2 \text{V} \\ &I_{C} = 10 \text{A}, \ V_{CE} = 2 \text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(SAT)}	_	21 55 150 160 350	30 75 200 210 440	mV	$\begin{split} &I_{C}=0.2A,I_{B}=20\text{mA}\\ &I_{C}=0.5A,I_{B}=20\text{mA}\\ &I_{C}=1A,I_{B}=10\text{mA}\\ &I_{C}=2A,I_{B}=100\text{mA}\\ &I_{C}=4.5A,I_{B}=200\text{mA} \end{split}$
Base-Emitter Saturation Voltage (Note 11)	V _{BE(SAT)}	_	900	1000	mV	$I_C = 3A$, $I_B = 100mA$
Base-Emitter Turn-on Voltage (Note 11)	V _{BE(ON)}	_	825	950	mV	I _C = 3A, V _{CE} = 2V
Transitional Frequency	f⊤	_	140	_	MHz	I _C = 50mA, V _{CE} = 10V, f = 100MHz
Output Capacitance	C _{obo}	_	21	30	pF	V _{CB} = 10V, f = 1MHz
Cuitakin n Tim a	ton		162		ns	$V_{CC} = 50V, I_C = 2A,$
Switching Time	t _{OFF}		900	_	ns	$I_{B1} = -I_{B2} = \pm 20 \text{mA}$

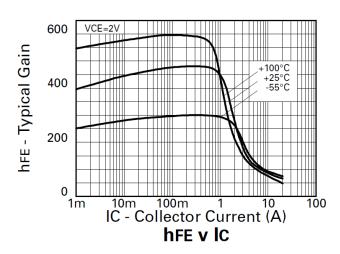
Note: 11. Measured under pulsed conditions. Pulse width = $300\mu s$. Duty cycle $\leq 2\%$.

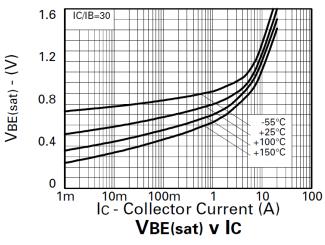


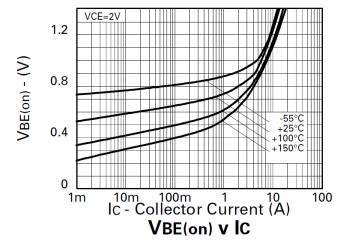
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)









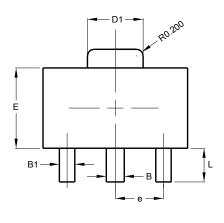


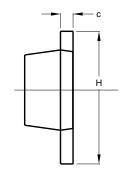


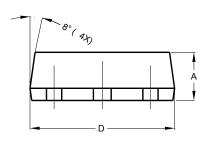
Package Outline Dimensions

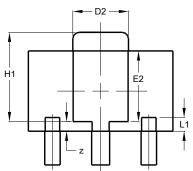
Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89







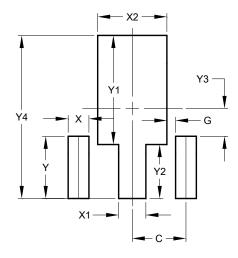


SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
z	0.20	0.40	0.30		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	Value (in mm)		
С	1.500		
G	0.244		
Х	0.580		
X1	0.760		
X2	1.933		
Υ	1.730		
Y1	3.030		
Y2	1.500		
Y3	0.770		
Y4	4.530		



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